

DATA SHEET

BLT71/8 UHF power transistor

Preliminary specification
File under Discrete Semiconductors, SC08b

1996 Feb 06

UHF power transistor

BLT71/8

FEATURES

- High efficiency
- Very high gain
- Internal pre-matched input
- Low supply voltage.

APPLICATIONS

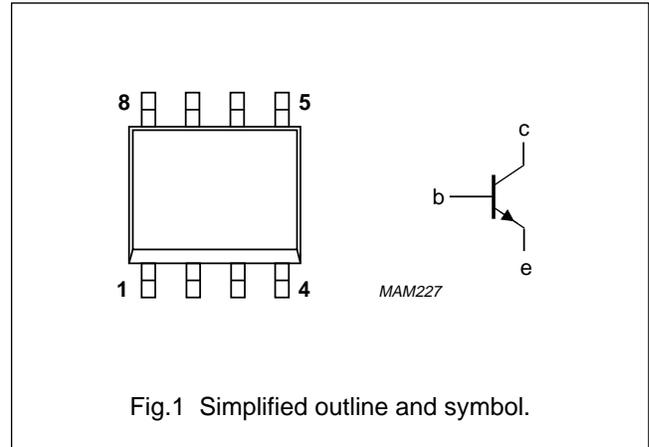
- Hand-held radio equipment in common emitter class-AB operation for 900 MHz communication band.

PINNING - SOT96-1

PIN	SYMBOL	DESCRIPTION
1, 8	b	base
2, 4, 5, 7	e	emitter
3, 6	c	collector

DESCRIPTION

NPN silicon planar epitaxial transistor encapsulated in a plastic SOT96-1 (SO8) SMD package.



QUICK REFERENCE DATA

RF performance at $T_s \leq 60$ °C in a common emitter test circuit.

MODE OF OPERATION	f (MHz)	V _{CE} (V)	P _L (W)	G _p (dB)	η_c (%)
CW, class-AB	900	4.8	1.2	≥11 typ. 13	≥55 typ. 63

UHF power transistor

BLT71/8

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	16	V
V_{CEO}	collector-emitter voltage	open base	–	8	V
V_{EBO}	emitter-base voltage	open collector	–	2.5	V
I_C	collector current (DC)		–	500	mA
P_{tot}	total power dissipation	$T_s = 60\text{ °C}$; note 1	–	2.9	W
T_{stg}	storage temperature		–65	+150	°C
T_j	operating junction temperature		–	175	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	$P_{tot} = 2.9\text{ W}$; $T_s = 60\text{ °C}$; note 1	40	K/W

Note to the “Limiting values” and “Thermal characteristics”

- T_s is the temperature at the soldering point of the collector pin.

CHARACTERISTICS $T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	open emitter; $I_C = 0.5\text{ mA}$	16	–	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	open base; $I_C = 10\text{ mA}$	8	–	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	open collector; $I_E = 0.1\text{ mA}$	2.5	–	V
I_{CES}	collector leakage current	$V_{CE} = 8\text{ V}$; $V_{BE} = 0$	–	0.1	mA
h_{FE}	DC current gain	$V_{CE} = 5\text{ V}$; $I_C = 100\text{ mA}$	25	–	
C_c	collector capacitance	$V_{CB} = 4.8\text{ V}$; $I_E = i_e = 0$; $f = 1\text{ MHz}$	–	7	pF
C_{re}	feedback capacitance	$V_{CE} = 4.8\text{ V}$; $I_C = 0$; $f = 1\text{ MHz}$	–	5	pF

UHF power transistor

BLT71/8

APPLICATION INFORMATION

RF performance at $T_s \leq 60^\circ\text{C}$ in a common emitter test circuit (note 1).

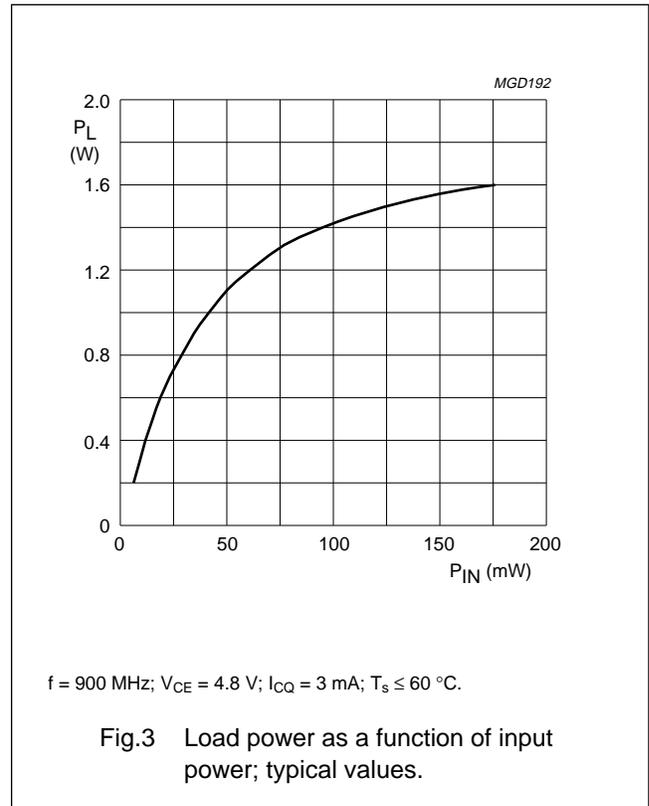
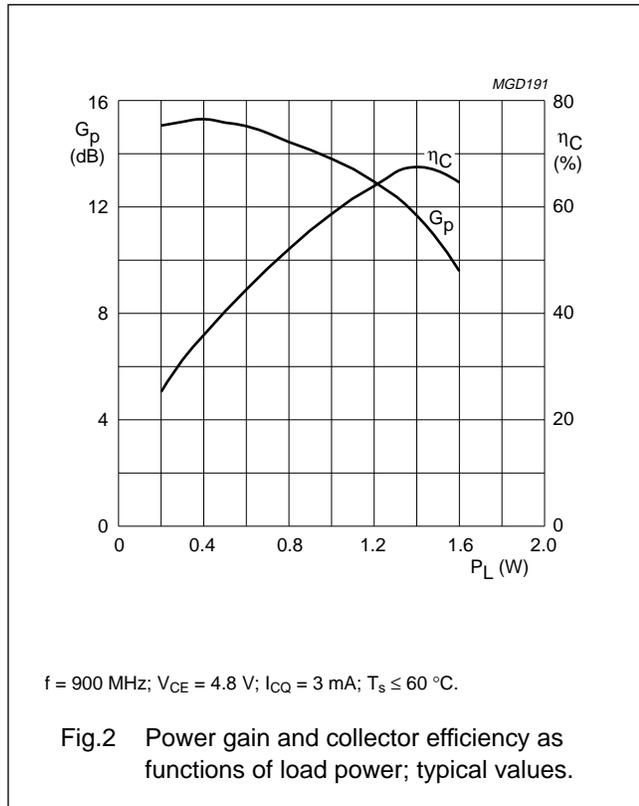
MODE OF OPERATION	f (MHz)	V _{CE} (V)	I _{CQ} (mA)	P _L (W)	G _p (dB)	η_c (%)
CW, class-AB	900	4.8	3	1.2	≥ 11 typ. 13	≥ 55 typ. 63

Note

1. T_s is the temperature at the soldering point of the collector pin.

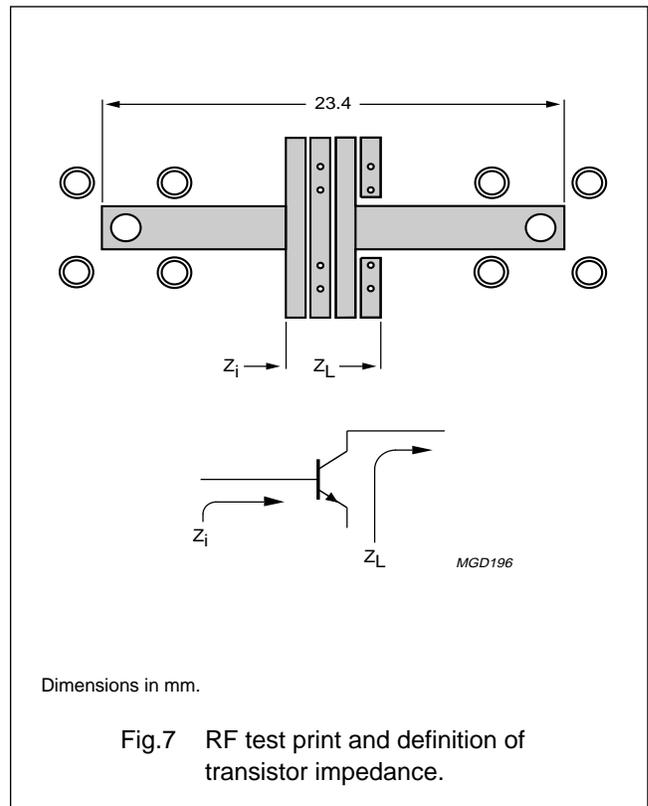
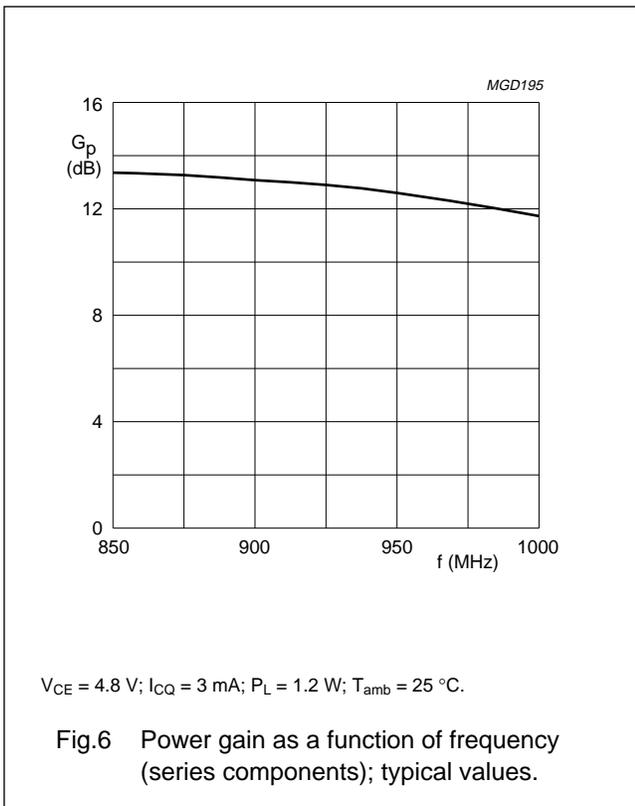
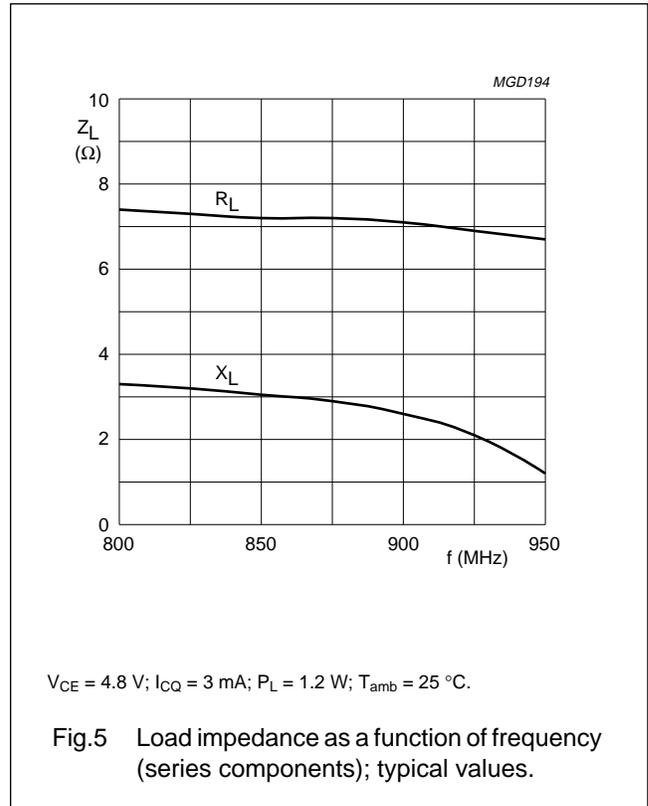
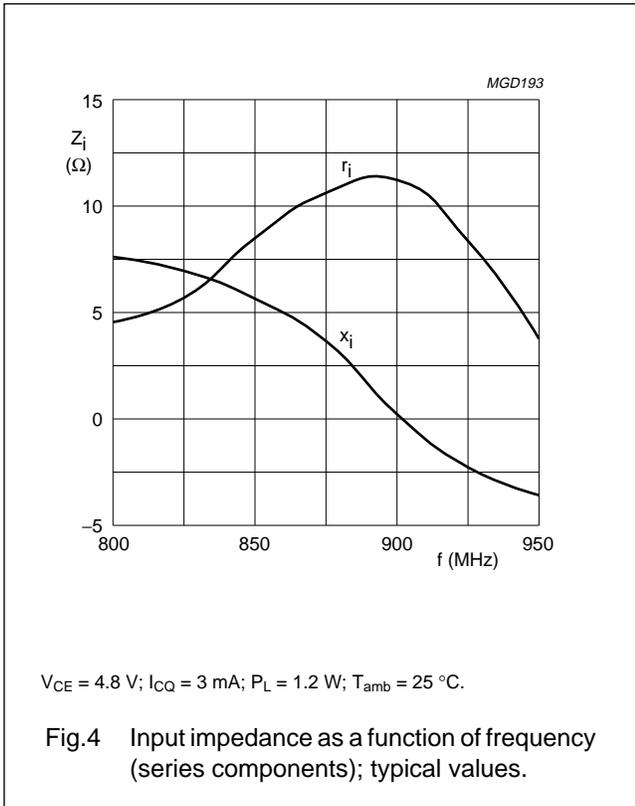
Ruggedness in class-AB operation

The BLT71/8 is capable of withstanding a load mismatch corresponding to VSWR = 6 : 1 through all phases under the following conditions: f = 900 MHz; V_{CE} = 6.5 V; I_{CQ} = 3 mA; P_L = 1.2 W; $T_s \leq 60^\circ\text{C}$.



UHF power transistor

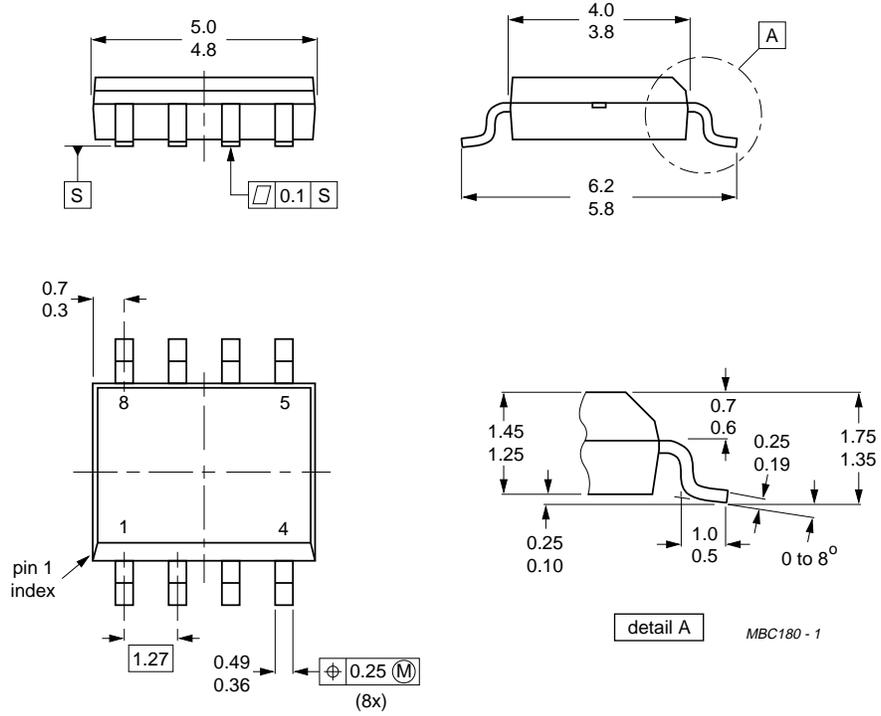
BLT71/8



UHF power transistor

BLT71/8

PACKAGE OUTLINE



Dimensions in mm.

Fig.8 SOT96-1.

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BLT71/8

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.